

L Number	Hits	Search Text	DB	Time stamp
1	24614	((pull-up) or pullup or load) adj2 (transistor or \$2fet or device or element)	USPAT	2004/09/29 23:45
2	17193	static adj3 (memory or storage)	USPAT	2004/09/29 23:46
3	21545	sram	USPAT	2004/09/29 23:46
4	28367	(static adj3 (memory or storage)) or sram	USPAT	2004/09/29 23:46
5	2426	((static adj3 (memory or storage)) or sram) and (((pull-up) or pullup or load) adj2 (transistor or \$2fet or device or element))	USPAT	2004/09/29 23:47
6	2405068	body or well	USPAT	2004/09/29 23:47
7	31569	forward\$3 near2 bias\$3	USPAT	2004/09/29 23:48
8	2674	(body or well) with (forward\$3 near2 bias\$3)	USPAT	2004/09/29 23:49
9	89	((static adj3 (memory or storage)) or sram) and (((pull-up) or pullup or load) adj2 (transistor or \$2fet or device or element))) and ((body or well) with (forward\$3 near2 bias\$3))	USPAT	2004/09/29 23:49
10	33	forward near2 body near2 bias near2 (voltage or potential)	USPAT	2004/09/30 00:22
12	0	(forward near2 body near2 bias near2 (voltage or potential)) and (((static adj3 (memory or storage)) or sram) and (((pull-up) or pullup or load) adj2 (transistor or \$2fet or device or element))) and ((body or well) with (forward\$3 near2 bias\$3))	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/29 23:51
11	1	(forward near2 body near2 bias near2 (voltage or potential)) and (((static adj3 (memory or storage)) or sram) and (((pull-up) or pullup or load) adj2 (transistor or \$2fet or device or element))) and ((body or well) with (forward\$3 near2 bias\$3))	USPAT	2004/09/30 00:11
13	1	((forward near2 body near2 bias near2 (voltage or potential)) and (((static adj3 (memory or storage)) or sram) and (((pull-up) or pullup or load) adj2 (transistor or \$2fet or device or element))) and ((body or well) with (forward\$3 near2 bias\$3)))) and sram	USPAT	2004/09/30 00:21
14	779710	switch\$3	USPAT	2004/09/30 00:21
15	12031	sram and switch\$3	USPAT	2004/09/30 00:22
16	3061	forward near2 bias near2 (voltage or potential)	USPAT	2004/09/30 00:23
17	290	switch\$3 with (forward near2 bias near2 (voltage or potential))	USPAT	2004/09/30 00:23
19	0	sram and (switch\$3 with (forward near2 bias near2 (voltage or potential)))	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 00:24
18	2	sram and (switch\$3 with (forward near2 bias near2 (voltage or potential)))	USPAT	2004/09/30 00:24

L Number	Hits	Search Text	DB	Time stamp
1	21545	sram	USPAT	2004/09/30 00:33
2	2195	bias adj2 voltage adj2 (generator or circuit)	USPAT	2004/09/30 00:34
3	2405068	body or well	USPAT	2004/09/30 00:34
4	116	sram and (bias adj2 voltage adj2 (generator or circuit)) and (body or well)	USPAT	2004/09/30 00:35
5	11499	forward adj2 bias	USPAT	2004/09/30 00:35
7	0	(sram and (bias adj2 voltage adj2 (generator or circuit)) and (body or well)) and (forward adj2 bias)	US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/09/30 00:35
6	33	(sram and (bias adj2 voltage adj2 (generator or circuit)) and (body or well)) and (forward adj2 bias)	USPAT	2004/09/30 00:35